

3-Phase Motor Driver IC

ECN30624 Product Specification

Rev. 4

1. Product Description

1.1 Features

- (1) Maximum Ratings: 600VDC/3.0A, suitable for the system from 200VAC to 240VAC
- (2) PWM control of top and bottom arm IGBTs is possible with six control signals
- (3) Six IGBTs, six FWDs (Free-Wheeling Diodes), drivers for IGBTs, protection circuits, etc. integrated into a single chip, resulting in space reduction
- (4) Drives a motor using a high voltage DC power supply and a low voltage DC power supply (15V)
- (5) Motor under free run condition detected by built-in back electromotive force (hereinafter called "back EMF") detection circuit
- (6) A capacitor for top arm power supply is built in, so external capacitor is not required
- (7) Lineup of four packages, DIP26, SOP26, SOP26R, and DIP26N ensuring insulation distance for high voltage pins

1.2 Functions

- (1) Back EMF detection (Two phases)
- (2) Prevention function against simultaneous ON of top and bottom arm IGBTs
- (3) Over-current protection (detects at 0.8V)
- (4) Over temperature protection
- (5) Fault function (Over-current protection, over temperature protection, Vcc low-voltage detection, shutdown function)
- (6) Protection recovery time adjusting function (automatic recovery)
- (7) Vcc low-voltage detection
- (8) 5V power supply circuit
- (9) Shutdown function

1.3 Block Diagram of IC

FIGURE 1.3.1 shows block diagram.

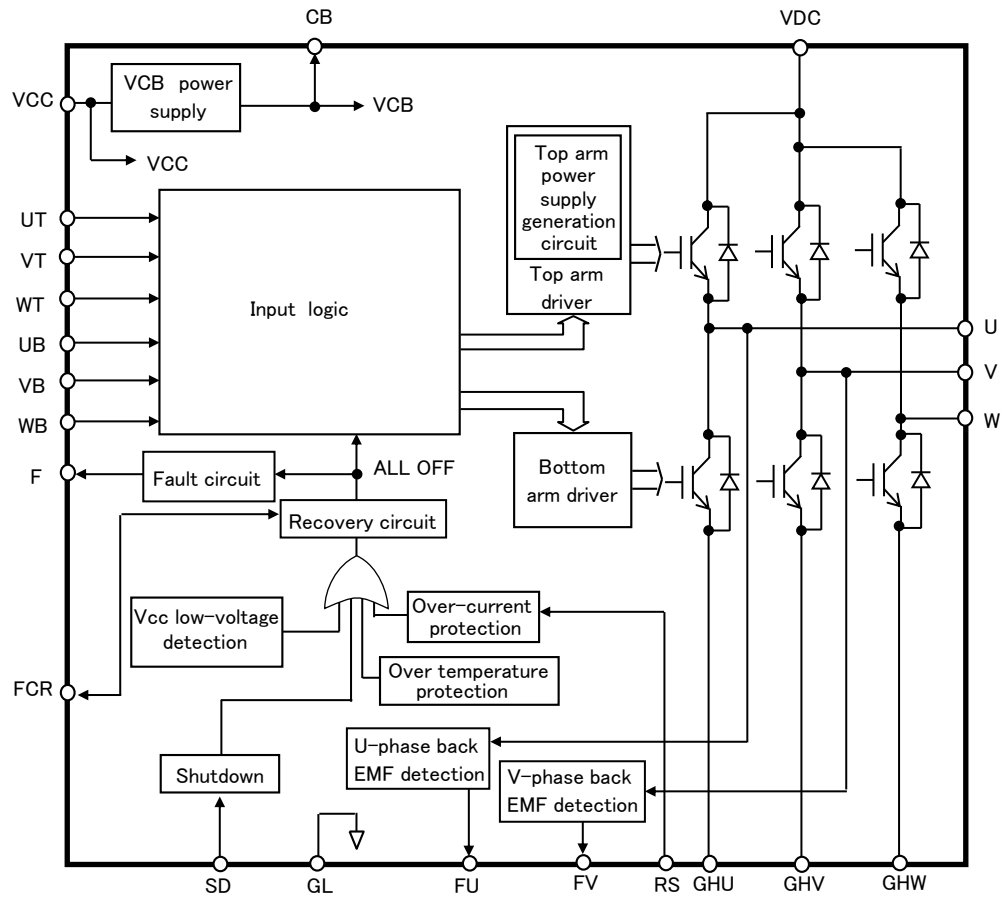


FIGURE 1.3.1 Block Diagram of IC

1.4 Package

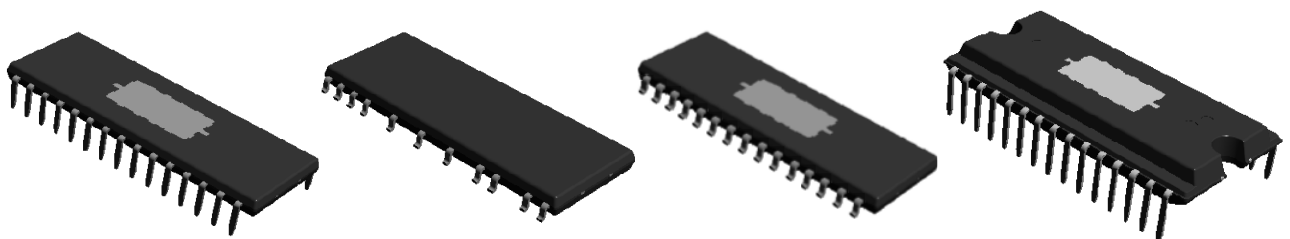
ECN30624P
(Package: DIP26)ECN30624F
(Package: SOP26)ECN30624R
(Package: SOP26R)ECN30624PN
(Package: DIP26N)

FIGURE 1.4.1 Package of ECN30624

2. Specification**2.1 Maximum Ratings****TABLE 2.1.1 Maximum Ratings**

Condition: Ta=25°C

No.	Item		Symbol	Pin	Rating	Unit	Remarks
1	Output device withstand voltage		VDCM	VDC U, V, W	600	V	
2	Vcc power supply voltage		VCC	VCC	18	V	
3	Input voltage		VIN	UT, VT, WT, UB, VB, WB, RS, SD, FCR	-0.5 to VCB+0.5	V	
4	Output current	Pulse	IP	U, V, W	3.0	A	Note 1
5		DC	IDC		2.0		
6	Fault output voltage		Vflt	F	-0.5 to Vcc+0.5	V	
7	FU, FV output voltage		VFU, VFV	FU, FV	-0.5 to VCB+0.5	V	
8	VCB supply output current		ICBMAX	CB	50	mA	
9	Junction operating temperature		Tjop	—	-40 to +135	°C	Note 2
10	Junction temperature		Tj	—	+150	°C	
11	Storage temperature		Tstg	—	-40 to +150	°C	

Note 1: Output IGBTs can handle this peak current.

Note 2: Thermal resistance

Between junction and case: Rjc = 3°C/W (Reference value)

2.2 Electrical Characteristics

TABLE 2.2.1 Electrical Characteristics (1/2)

Suffix (T: Top arm, B: Bottom arm)

Condition: Ta=25°C

No.	Item	Symbol	Pin	Min.	Typ.	Max.	Unit	Condition
1	Standby current	IDCH	VDC	—	0	0.1	mA	UT,VT,WT,UB,VB,WB=0V VDC=325V, VCC=15V, ICB=0A
2		ICC	VCC	—	5	10	mA	
3	IGBT collector-emitter saturation voltage	VONT	U, V, W	—	2.0	3.0	V	I=0.7A, VCC=15V
4		VONB		—	2.0	3.0	V	
5	Free-wheeling diode forward voltage	VFDT	U, V, W	—	1.6	2.8	V	I=0.7A
6		VFDB		—	1.6	2.8	V	
7	Output delay time	Turn ON	U, V, W	—	0.7	1.1	μs	VDC=325V, VCC=15V I=0.7A, Resistance load
8		TdONB		—	0.7	1.1	μs	
9		Turn OFF		—	0.7	1.1	μs	
10		TdOFFB		—	0.7	1.1	μs	
11	Minimum pulse width	TMIN	U, V, W	0.5	—	—	μs	VCC=15V Note 1
12	RS input current	IILRS	RS	−100	—	—	μA	VCC=15V, RS=0V Note 2
13	UT,VT,WT, UB,VB,WB, inputs	Voltage	UT, VT, WT, UB, VB, WB	2.5	—	—	V	VCC=15V
14		VIL		—	—	1.0	V	
15		Current		—	—	100	μA	
16		IIL		−10	—	—	μA	
17	VCB supply output	Voltage	CB	4.5	5.0	5.5	V	VCC=15V, ICB=0A
18		Current		—	—	45	mA	
19	FU, FV output resistance	RONFU, RONFV	FU, FV	—	0.4	0.8	kΩ	IFU, IFV=1mA, VCC=15V Note 4
20	Back EMF detection level	VIHE	U, V	5.5	—	—	V	VCC=15V, UT,VT,WT,UB,VB,WB=0V
21		VILE		—	—	2.5	V	
22	F output resistance	RONF	F	—	0.9	1.8	kΩ	IF=1mA, VCC=15V Note 5
23	Over-current protection	Reference voltage	RS, F, FCR	0.72	0.80	0.88	V	VCC=15V
24		Delay time		—	1.7	3.0	μs	
25	Over temperature protection	Operating temperature	U, V, W, F, FCR	135	160	185	°C	VCC=15V
26		Hysteresis		—	25	—	°C	
27	Vcc low-voltage detection	Operating voltage	VCC, U, V, W,	11.0	12.0	12.9	V	
28		Recovery voltage	F	11.1	12.5	13.0	V	

TABLE 2.2.1 Electrical Characteristics (2/2) Suffix (T: Top arm, B: Bottom arm) Condition: Ta=25°C

No.	Item		Symbol	Pin	Min.	Typ.	Max.	Unit	Condition
29	Shutdown function	Operating voltage	Vref2	SD, F, FCR	1.15	1.23	1.31	V	VCC=15V
30		Recovery voltage	Vref3		1.10	1.18	1.26	V	
31		Delay time	Tref2		—	2.5	5.0	μs	
32	SD pin input current		IIHSD	SD	—	—	2	μA	VCC=15V, SD=4.5V Note 6
33			IILSD		-2	—	—	μA	VCC=15V, SD=0V Note 6
34	FCR output resistance		RONFCR	FCR	—	0.4	0.8	kΩ	IFCR=1mA, VCC=15V Note 7
35	Protection recovery time		Trs1	FCR	—	1.0	2.0	ms	When VCC=15V, CFCR=1000pF is connected to GL, and RFCR=1MΩ is connected to CB Note 8
36			Trs2		20	-	-	μs	When VCC=15V, and RFCR=10kΩ is connected to CB Note 9

Note 1: The minimum pulse width to be able to turn on and off top and bottom arms.

Note 2: Internal pull-up resistor is typically 200kΩ. The equivalent circuit is shown in FIGURE 2.2.1.

Note 3: Internal pull-down resistor is typically 200kΩ. The equivalent circuit is shown in FIGURE 2.2.2.

Note 4: The equivalent circuit is shown in FIGURE 2.2.3.

Note 5: The equivalent circuit is shown in FIGURE 2.2.4.

Note 6: The equivalent circuit is shown in FIGURE 2.2.5.

Note 7: The equivalent circuit is shown in FIGURE 2.2.6.

Note 8: Typical value when the protection recovery time adjusting function is enabled. Details are shown in Section 2.4.6.

Note 9: Typical value when the protection recovery time adjusting function is disabled. Details are shown in Section 2.4.6.

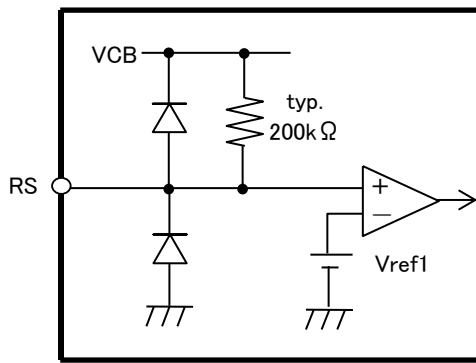


FIGURE 2.2.1 Equivalent Circuit Around RS Pin

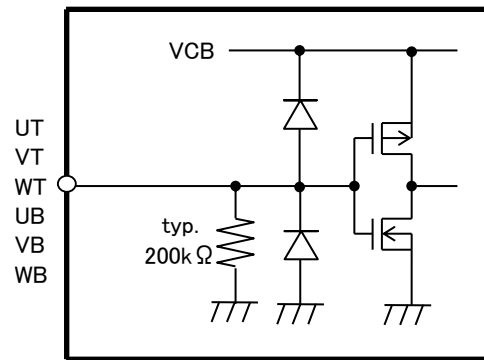


FIGURE 2.2.2 Equivalent Circuit Around UT, VT, WT, UB, VB, WB Pins

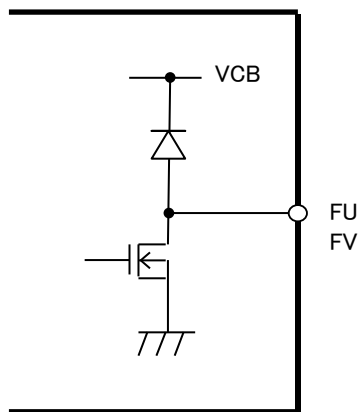


FIGURE 2.2.3 Equivalent Circuit Around FU, FV Pins

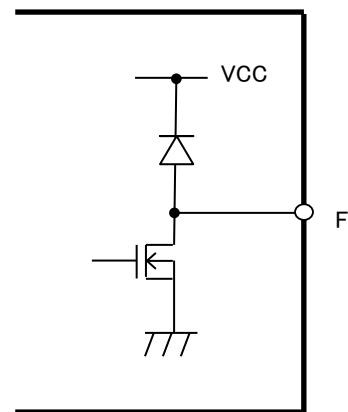


FIGURE 2.2.4 Equivalent Circuit Around F Pin

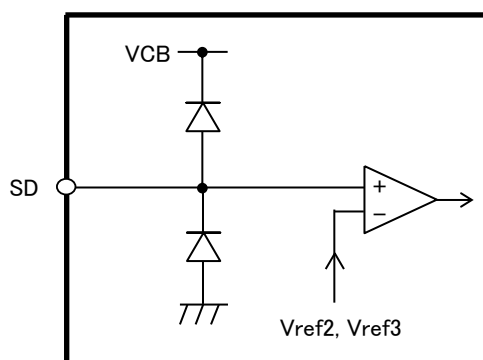


FIGURE 2.2.5 Equivalent Circuit Around SD Pin

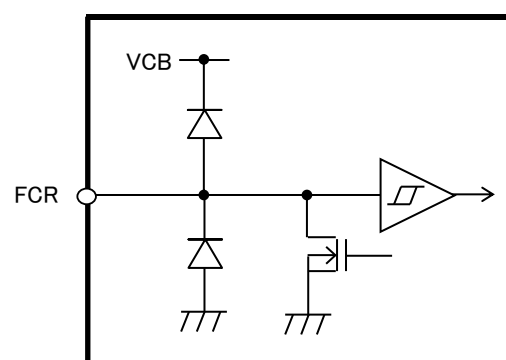


FIGURE 2.2.6 Equivalent Circuit Around FCR Pin

2.3 Operating Condition

TABLE 2.3.1 Operating Condition

No.	Item	Symbol	Pin	Min.	Typ.	Max.	Unit	Condition
1	Supply voltage	VDCop	VDC	100	325	450	V	
2		VCCop	VCC	13.5	15.0	16.5	V	
3	GH voltage	Vgh	GHU, GHV, GHW	-1.2	—	1.2	V	Based on GL pin
4	Dead time	Tdt	UT, VT, WT, UB, VB, WB	1.0	—	—	μs	
5	PWM frequency	fPWM	UT, VT, WT, UB, VB, WB	14	—	30	kHz	Note 1

Note 1. Depending on the usage conditions, this frequency may go in an audible band, generating noise.

2.4 Functions and Operations

2.4.1 Truth Table

TABLE 2.4.1.1 Truth Table

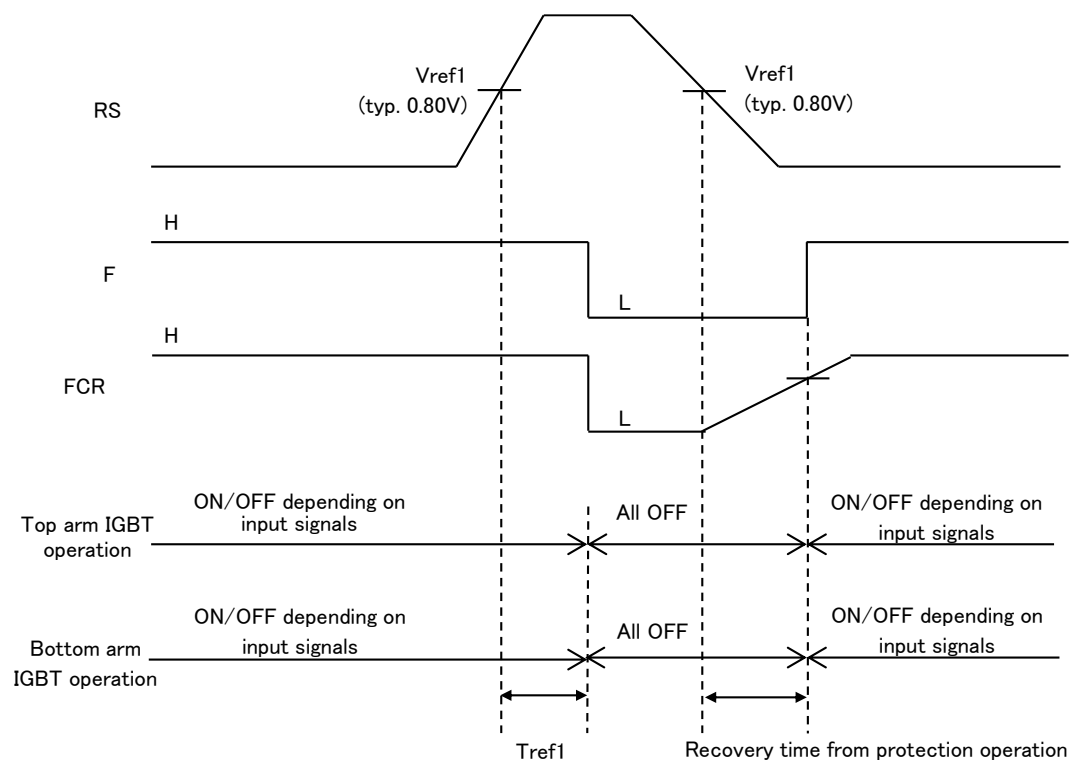
Input UT, VT, WT UB, VB, WB	IGBT operation
L	OFF
H Note 1	ON

Note 1: When the top input and bottom input in the same phase are “H” simultaneously, the top and bottom arm IGBTs in this phase are both off.

2.4.2 Over-current Protection

When the voltage at the RS pin reaches the over-current protection reference voltage (V_{ref1} , typ. 0.80V), the F output is “L”, and all IGBTs (top and bottom arms) are turned off. When the voltage at the RS pin drops below the over-current protection reference voltage (V_{ref1} , typ. 0.80V) and the over-current protection recovery time passes, the F output is “H”, and the IC automatically returns to a state in which the IGBTs operate depending on input signals. The protection recovery time is adjustable using FCR pin, and the adjustment method is shown in Section 2.4.6.

FIGURE 2.4.2.1 shows the timing chart for the over-current protection operation.

**FIGURE 2.4.2.1 Timing Chart for Over-current Protection Operation**

2.4.3 Vcc Low-voltage Detection

We call the Vcc low-voltage detection “LVSD”. When the Vcc voltage drops below the LVSD operating voltage (LVSDON, typ.12.0V), the F output is “L”, and all IGBTs (top and bottom arms) are turned off. When the Vcc voltage goes up to a level equal to or exceeding the LVSD recovery voltage (LVSDOFF, (typ. 12.5V) and the protection recovery time (Trs2) passes, the F output is “H”, and the IC automatically returns to a state in which the IGBTs operate depending on input signals. The protection recovery time is fixed at Trs2.

FIGURE 2.4.3.1 shows the timing chart for the Vcc low-voltage detection operation.

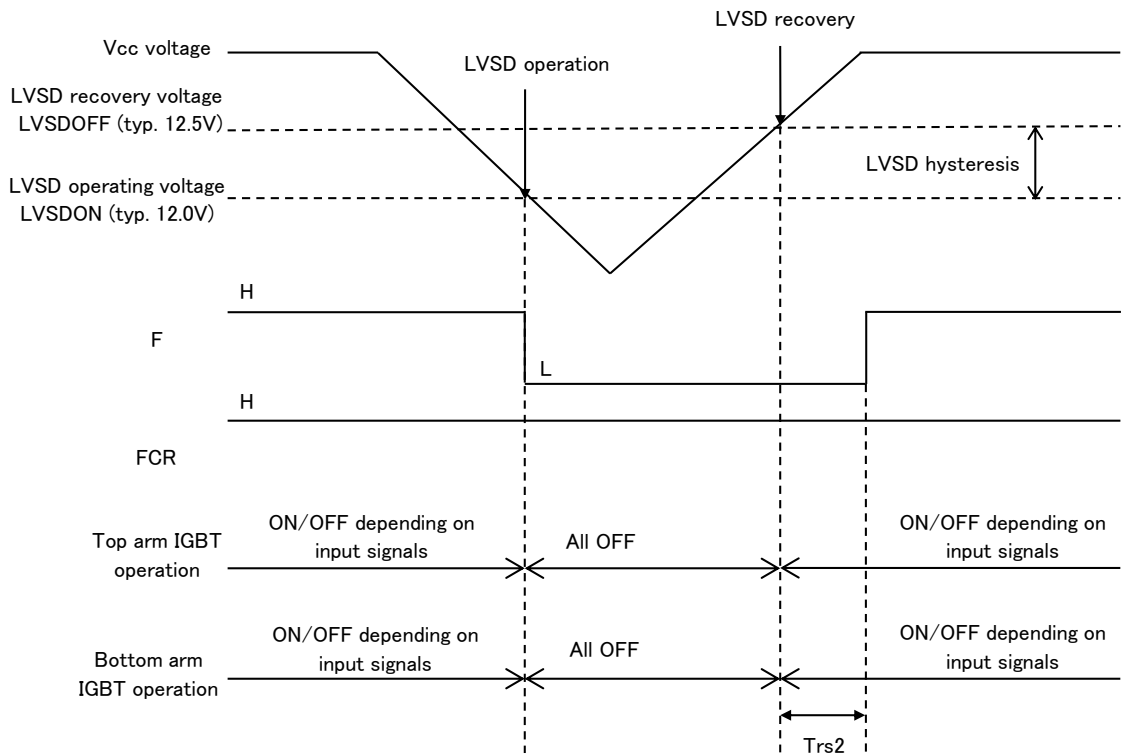


FIGURE 2.4.3.1 Timing Chart for Vcc Low-voltage Detection Operation

2.4.4 Over Temperature Protection

We call the Over temperature protection “TSD”. When the IC temperature exceeds the TSD operating temperature (TSDON, typ. 160°C), the F output is “L”, and all IGBTs (top and bottom arms) are turned off. When the IC temperature goes down the hysteresis (TSDHYS, typ. 25°C) from the TSD operating temperature (TSDON, typ. 160°C) and protection recovery time passes, the F output is “H”, and the IC automatically returns to a state in which the IGBTs operate depending on input signals. The protection recovery time is adjustable using FCR pin, and the adjustment method is shown in Section 2.4.6.

FIGURE 2.4.4.1 shows the timing chart for the over temperature protection operation.

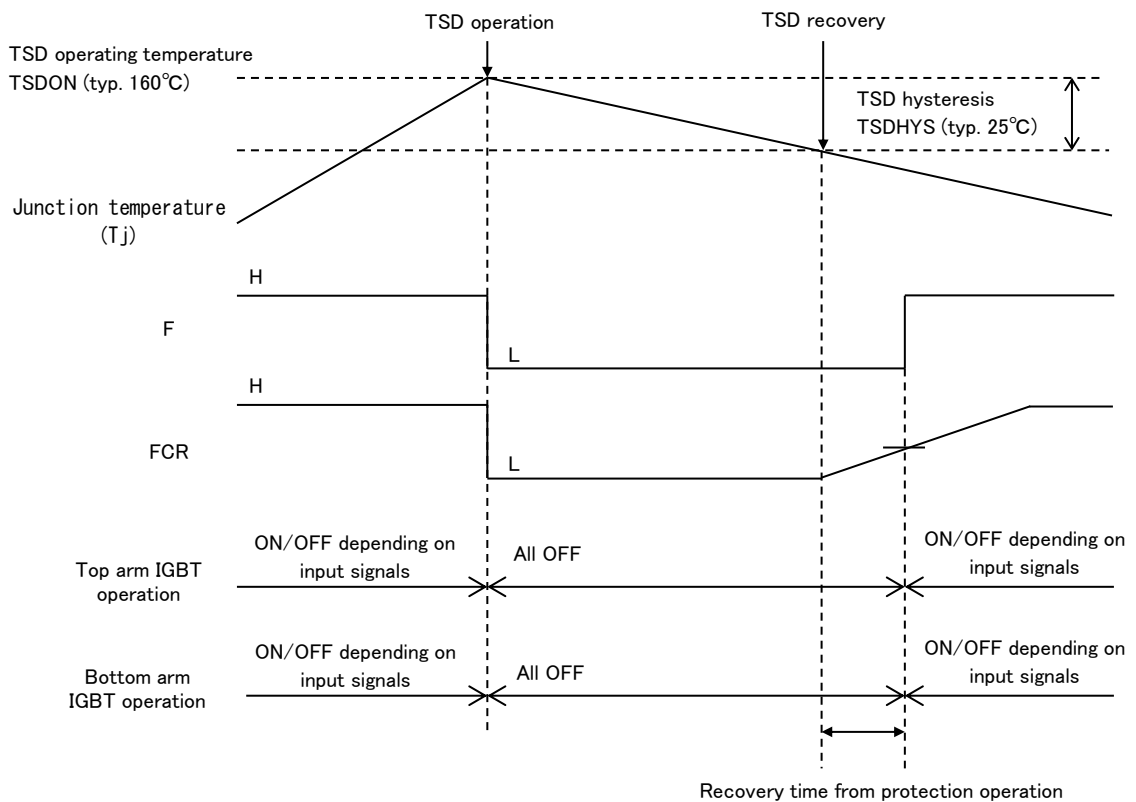


FIGURE 2.4.4.1 Timing Chart for Over Temperature Protection Operation

2.4.5 Shutdown Function

When the voltage at the SD pin reaches the shutdown operating voltage (V_{ref2} , typ. 1.23V), the F output is “L”, and all IGBTs (top and bottom arms) are turned off. After that, when the voltage at the SD pin falls below the shutdown recovery voltage (V_{ref3} , typ. 1.18V) and protection recovery time passes, the F output is “H”, and the IC automatically returns to a state in which the IGBTs operate depending on input signals. The protection recovery time is adjustable using the FCR pin, and the adjustment method is shown in Section 2.4.6.

This function can be used as an over-voltage protection when over-voltage is applied on the VDC pin. The operating voltage and recovery voltage of the over-voltage protection are adjustable by the resistance values of external resistors ROVP1 and ROVP2 which are connected between the VDC pin and GL pin. These voltages can be calculated using the following equations:

$$\text{Over-voltage protection operating voltage: } OV_{PON}(V) = \frac{ROVP1(\Omega) + ROVP2(\Omega)}{ROVP2(\Omega)} \times V_{ref2}(V)$$

$$\text{Over-voltage protection recovery voltage: } OV_{POFF}(V) = \frac{ROVP1(\Omega) + ROVP2(\Omega)}{ROVP2(\Omega)} \times V_{ref3}(V)$$

When this function is not used, connect the SD pin to the GL pin. FIGURE 2.4.5.1 shows the timing chart for shutdown operation.

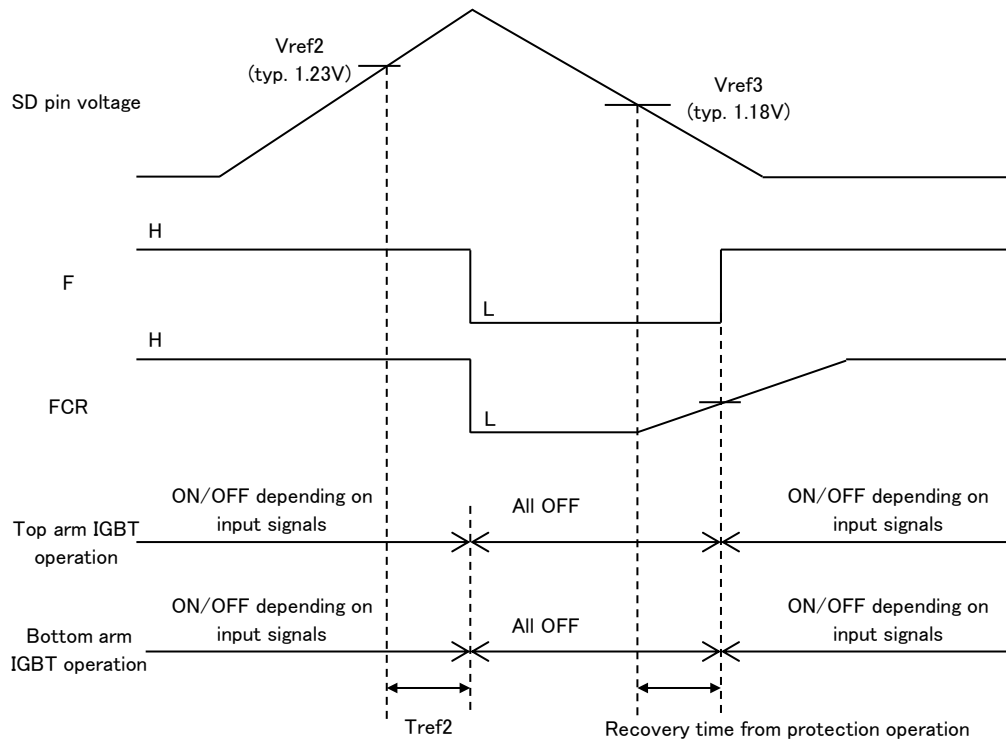


FIGURE 2.4.5.1 Timing Chart for Shutdown Operation

2.4.6 Protection Recovery Time Adjusting Function

The FCR pin is used for adjusting the protection recovery time. Connect the RFCR and CFCR between the CB pin and GL pin. Then, connect the midpoint of the CB pin and GL pin to the FCR pin. See the connection example in FIGURE3.1.1. When any of the protection functions (over-current, over temperature, or shutdown function) operates, the voltage at the FCR pin is “L”. After that, when the protection recovery conditions are satisfied and protection recovery time (Trs) determined by RFCR and CFCR passes, the F output is “H”, and the IC returns to a state in which the IGBTs operate depending on input signals. On the other hand, when RFCR=10kΩ is connected between the CB pin and FCR pin with the CFCR unconnected, after the protection recovery conditions are satisfied and protection recovery time (Trs2) determined by the internal circuit passes, the F output is “H”, and the IC returns to a state in which the IGBTs operate depending on input signals. When the Vcc low-voltage detection operates, the protection recovery time is Trs2 regardless of RFCR and CFCR values.

Trs can be calculated as follows.

$$\text{Trs (ms)} = \text{Trs1 (ms)} * \times \frac{\text{RFCR(M}\Omega\text{)} \times \text{CFCR(pF)}}{1(\text{M}\Omega) \times 1000(\text{pF})}$$

* Trs1 (typ. 1ms)

Please set RFCR to 500kΩ to 2MΩ and CFCR to 1000pF to 5000pF as a guide.

TABLE 2.4.6 shows the relationship between each protection function and protection recovery time.

FIGURE 2.4.6.1 shows the timing chart in case of FCR pin connected to RFCR and CFCR. FIGURE 2.4.6.2 shows the timing chart in case of RFCR=10kΩ connected to FCR pin with CFCR unconnected.

TABLE 2.4.6 Relationship Between Protection and Protection Recovery Time

Protection function	Protection recovery time	
	When protection recovery time adjusting function is enabled (When RFCR, CFCR are connected to FCR pin)	When protection recovery time adjusting function is disabled (When RFCR=10kΩ is connected to FCR pin with CFCR unconnected)
Vcc low-voltage detection	Trs2	Trs2
Over-current protection	Trs	
Over temperature protection		
Shutdown function		

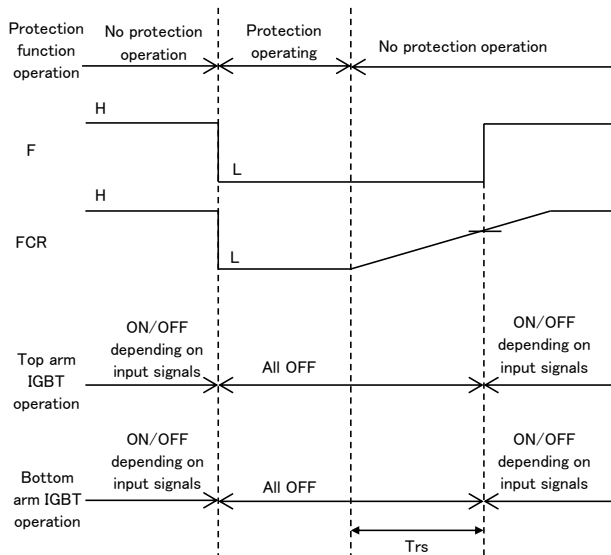


FIGURE 2.4.6.1
Timing Chart in Case of Protection Recovery Time Adjusting Function Enabled
(Except for Vcc low-voltage detection)

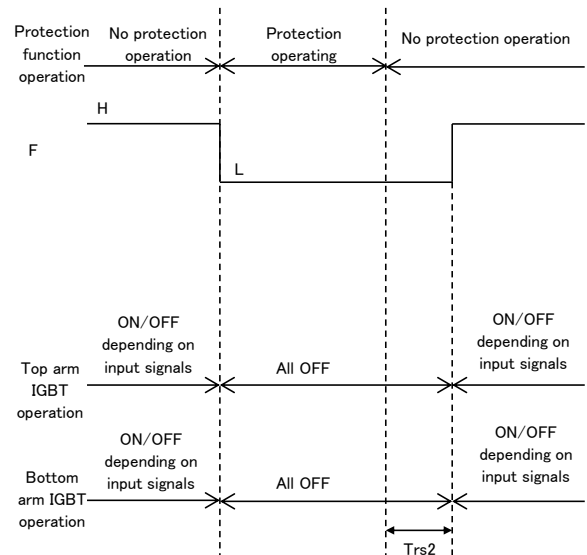
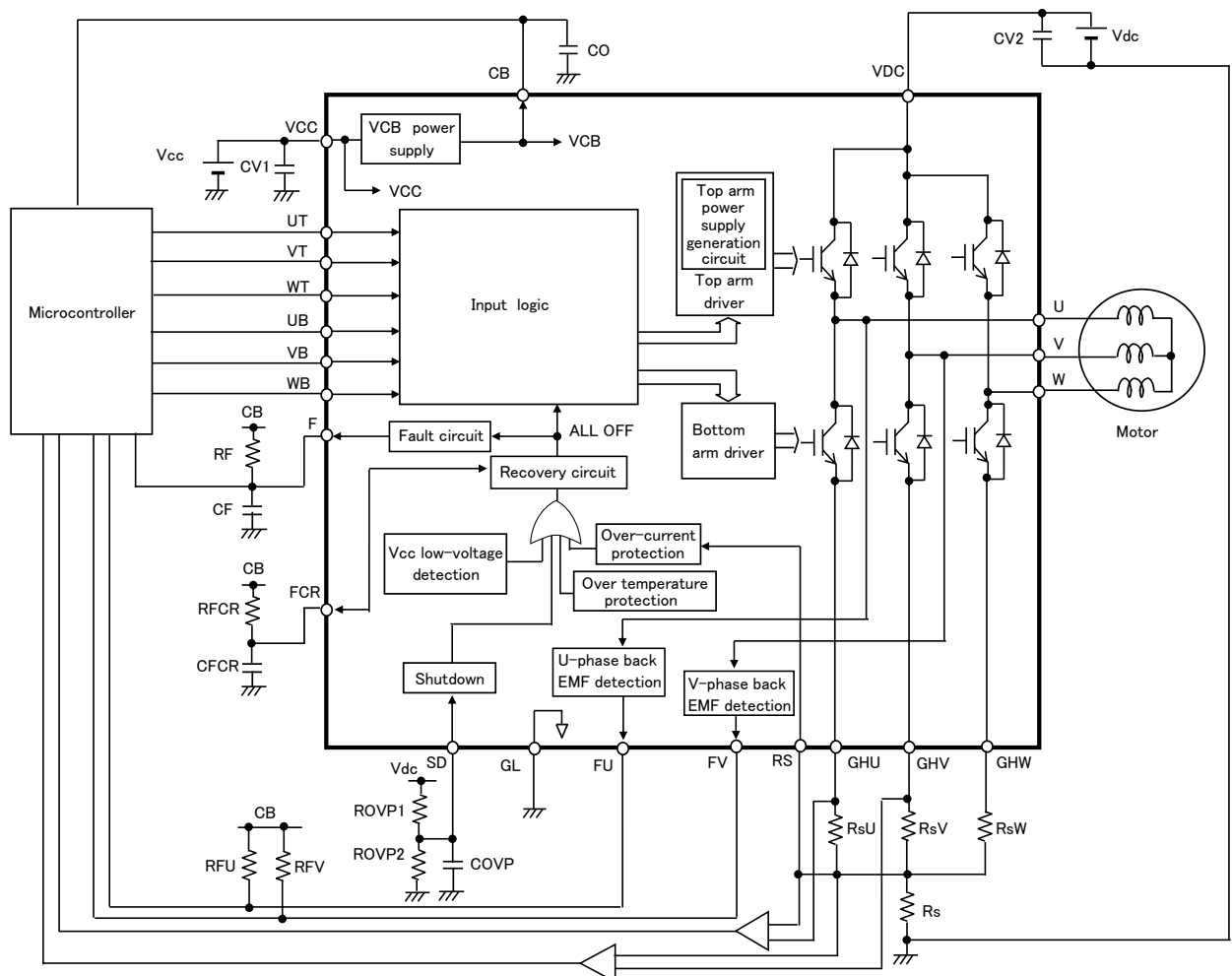


FIGURE 2.4.6.2
Timing Chart in Case of Protection Recovery Time Adjusting Function Disabled

3. Standard Applications**3.1 External Components****TABLE 3.1.1 External Components**

Component	Standard value	Usage	Remarks
C0	1 μ F $\pm$ 10%, 25V	Smooths the internal power supply (VCB)	
CV1	1 μ F $\pm$ 10%, 25V	Smooths the Vcc power supply	Note 1
CV2	33nF $\pm$ 10%, 630V	Smooths the Vdc power supply	Note 1
Rs	1 Ω $\pm$ 1%, 1W	Sets over-current protection	Note 2 for how to set Rs.
RFU, RFV	10k Ω $\pm$ 5%	For pull up	
CF	0.01 μ F $\pm$ 10%, 25V	Eliminates output noise of Fault signal	
RF	10k Ω $\pm$ 10%	For pull up	
CFCR	1000pF $\pm$ 10%, 25V	Sets protection recovery time	When the protection recovery time adjusting function is enabled, connect RFCR and CFCR to FCR pin.
RFCR	1M Ω $\pm$ 10%		
CFCR	–	–	When the protection recovery time adjusting function is disabled, connect RFCR to FCR pin and do not connect CFCR to FCR pin.
RFCR	10k Ω $\pm$ 10%	For pull up	
ROVP1	–	Sets over-voltage protection operating voltage/recovery voltage	Note 3 for how to set ROVP1.
ROVP2	–	Sets over-voltage protection operating voltage/recovery voltage	Note 3 for how to set ROVP2.
COVP	0.1 μ F $\pm$ 10%, 25V	Eliminates input noise of SD signal	Note 4

**FIGURE 3.1.1 Block Diagram and External Components of IC**

Note 1. Caution for smoothing capacitor

As necessary, increase the capacitance and add a zener diode in consideration of noise immunity. Mount each of the components close to the pins of the IC.

Note 2. Caution for Rs resistance setting

The over-current protection set value (IO) can be calculated as follows.

$$IO = V_{ref1}/R_s$$

Vref1: Over current protection reference voltage

Rs: Shunt resistance value

Delay time to turn output IGBT off (Tref1) and variability of Vref1, Rs need to be considered. Observe the output currents of the IC (the coil currents of the motor) and confirm a design margin.

Set the shunt resistance so that voltages of the GHU, GHV, and GHW pins are within the specified voltage range of GH pin (Vgh) shown in TABLE 2.3.1.

Note 3. Section 2.4.5 shows how to set the resistance values.

Note 4. When influence of noise or others is large, adjust the capacitance of the capacitor as necessary.

3.2 Input Pins (UT, VT, WT, UB, VB, WB)

In some applications, input pins may be sensitive to noise due to high impedance. If noise is detected at an input pin, the following resistor and/or capacitor should be added.

- Resistor : 5.6kΩ ± 5% pull-down resistor between the GL pin and input pins
- Capacitor : 470pF ± 20% ceramic capacitor close to the input pin

4. Safe Operation Area (SOA) and Derating**4.1 Safe Operation Area (SOA)**

The current and voltage at output pins must not be outside the SOA shown in FIGURE 4.1.1.

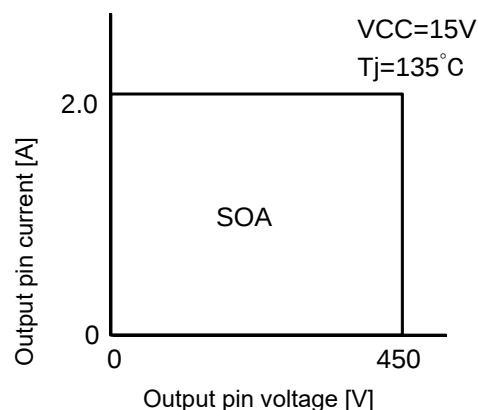


FIGURE 4.1.1 SOA

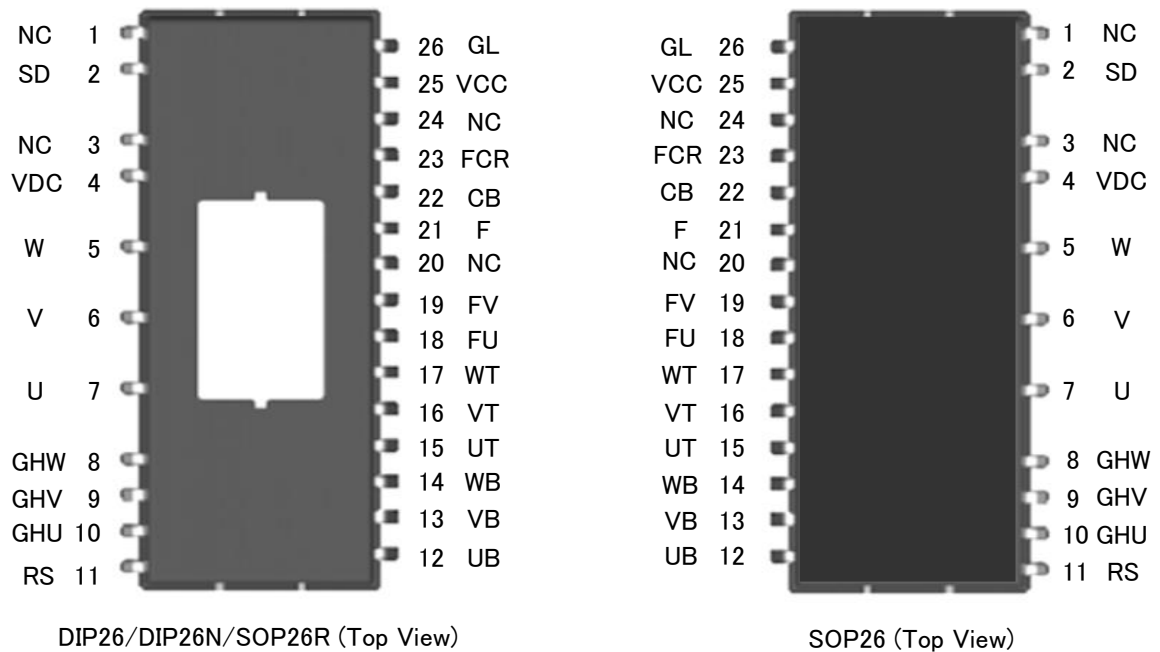
4.2 Shunt Resistor (Rs) Setting

Delay time to turn output IGBT off (Tref1) and variability of Vref1, Rs need to be considered, and the current must be below the curve of FIGURE 4.1.1.

4.3 General Design Derating Standards

(a) Temperature - Junction operating temperature must be kept under 110°C.

Junction operating temperature depends on various parameters such as power supply voltages, ambient temperature, load, heat dissipation routes, and output ON duty. Test it sufficiently by using actual systems.

5. Pin Locations**FIGURE 5.1 Pin Locations****6. Pin Assignments****TABLE 6.1 Pin Assignments**

Pin No.	Symbol	Pin functions	Remarks
1, 3, 20, 24	NC	No connection	Note 2
2	SD	For shutdown function	
4	VDC	High voltage power supply	Note 1
5	W	W-phase output	Note 1
6	V	V-phase output	Note 1
7	U	U-phase output	Note 1
8	GHW	Emitter of W-phase bottom arm IGBT and anode of W-phase bottom arm FWD	
9	GHV	Emitter of V-phase bottom arm IGBT and anode of V-phase bottom arm FWD	
10	GHU	Emitter of U-phase bottom arm IGBT and anode of U-phase bottom arm FWD	
11	RS	Input for over-current protection	
12	UB	Input control signal for U-phase bottom arm	
13	VB	Input control signal for V-phase bottom arm	
14	WB	Input control signal for W-phase bottom arm	
15	UT	Input control signal for U-phase top arm	
16	VT	Input control signal for V-phase top arm	
17	WT	Input control signal for W-phase top arm	
18	FU	U-phase back EMF signal output	
19	FV	V-phase back EMF signal output	
21	F	Fault signal output	
22	CB	VCB power supply output	
23	FCR	For adjusting protection recovery time	
25	VCC	Control power supply	
26	GL	Ground	

Note 1. High voltage pin.

Note 2. Not connected to the chip in the IC.

Note 3. The tab potential is the same as that of the GL pin. Set the tab potential to open or the same as that of GND. If the tab is mounted on the external cabinet of the motor for heat radiation purposes, the IC will not be able to withstand an insulation withstand voltage test in which a high voltage is applied between the external cabinet and the GND. Please insert an insulation sheet or something similar between the IC tab and the external cabinet.

7. Inspection

Hundred percent inspection shall be conducted on electric characteristics at room temperature. For the operating temperature and hysteresis of the over temperature protection, equivalent inspections are conducted at room temperature.

8. Precautions for Use

In this document, "MPSD" stands for Minebea Power Semiconductor Device Inc.

8.1 Countermeasures against Electrostatic Discharge (ESD)

- (a) Customers need to take precautions to protect ICs from electrostatic discharge (ESD). The material of the container or any other device used to carry ICs should be free from ESD, which can be caused by vibration during transportation. Use of electrically conductive containers is recommended as an effective countermeasure.
- (b) Everything that touches ICs, such as the work platform, machine, measuring equipment, and test equipment, should be grounded.
- (c) Workers should be high-impedance grounded (100k Ω to 1M Ω) while working with ICs, to avoid damaging the ICs by ESD.
- (d) Friction with other materials, such as high polymers, should be avoided.
- (e) When carrying a PCB with a mounted IC, ensure that the electric potential is maintained at a constant level using the short-circuit terminals and that there is no vibration or friction.
- (f) The humidity at an assembly line where ICs are mounted on circuit boards should be kept around 45 to 75 percent using humidifiers or such. If the humidity cannot be controlled effectively, using ionized air blowers (ionizers) is effective.

8.2 Output Short-circuit Protection

The MPSD IC could break by a short circuit (ex. load short). Therefore, external protection is needed.

8.3 Maximum Ratings

Regardless of changes in external conditions during use of the MPSD IC, the "maximum ratings" described in this document should never be exceeded when designing electronic circuits that employ the MPSD IC. If maximum ratings are exceeded, the MPSD IC may be damaged or destroyed. In no event shall MPSD be liable for any failure in the MPSD IC or any secondary damage resulting from use at a value exceeding the maximum ratings.

8.4 Derating Design

Continuous high-load operation (high temperatures, high voltages, large currents) should be avoided and derating design should be applied, even within the ranges of the maximum ratings, to ensure reliability.

8.5 Safe Design

The MPSD IC may fail due to accidents or unexpected surge voltages. Accordingly, adopt safe design features, such as redundancy and measures to prevent misuse, in order to avoid extensive damage in the event of a failure.

8.6 Application

If the MPSD IC is applied to the following uses where high reliability is required, obtain the document of permission from MPSD in advance.

- Automobile, Train, Vessel, etc.

Do not apply the MPSD IC to the following uses where extremely high reliability is required.

- Nuclear power control system, Aerospace instrument, Life-support-related medical equipment, etc.

8.7 Soldering

(1) DIP26, DIP26N Soldering condition

The peak temperature of flow soldering* must be less than 260°C, and the dip time must be less than 10 seconds. High stress by mounting, such as long time thermal stress by preheating, mechanical stress, etc., can lead to degradation or destruction. Make sure that your mounting method does not cause problem as a system.

* Flow soldering: Only pins enter a solder bath, while the resin or tab does not.

(2) SOP26, SOP26R Soldering condition

This power semiconductor product is lead-free. The recommended reflow soldering condition is shown in FIGURE 8.7.1. High stress by mounting, such as long time thermal stress by preheating, mechanical stress, etc., can lead to degradation or destruction. Make sure that your mounting method does not cause problem as a system.

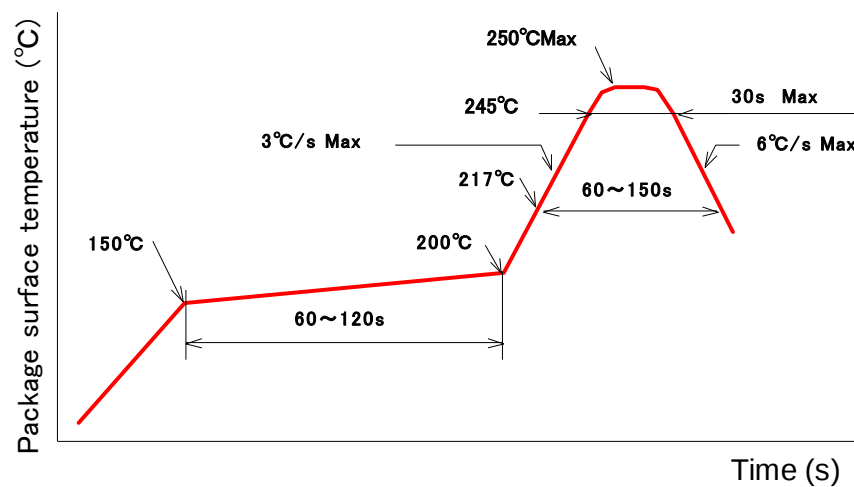


FIGURE 8.7.1 Recommended Conditions for Infrared Reflow or Air Reflow

(3) Reliability of solder connection

The reliability of solder connection depends on soldering condition, materials of circuit boards, footprint, etc. Test it sufficiently by heat cycle test, heat shock test, and so on after mounting ICs on circuit boards.

8.8 Storage Conditions

The following conditions are applied to ECN30624F/R (SOP26, SOP26R).

(1) Before opening the moisture prevention bag (aluminum laminate bag)

Temperature: less than 40°C

Humidity: less than 90%RH

Period: less than 12 months

(2) After opening the moisture prevention bag (aluminum laminate bag)

Temperature: 5°C to 30°C

Humidity: less than 60%RH

Period: less than 168 hours

※ When the period of (1) and (2) is likely to expire, store the ECN30624F/R (SOP26, SOP26R) in a drying furnace (10%RH or lower) at ordinary temperature.

(3) Baking process

When the period of (1) and (2) has expired, the ECN30624F/R (SOP26, SOP26R) should be baked in accordance with the following conditions. (However, when the ECN30624F/R (SOP26, SOP26R) is stored in a drying furnace (10%RH or lower) at ordinary temperature, there is no need to bake.) Do not bake the tape and the reel of the taping package because they are not heat resistant. Transfer the ECN30624F/R (SOP26, SOP26R) to a heat resistant container prior to baking.

Temperature: 125°C to 135°C

Period: more than 48 hours

8.9 Others

See “Instructions for Use of High-Voltage Monolithic ICs” and “Application Note” for other precautions and instructions on how to deal with these kinds of products.

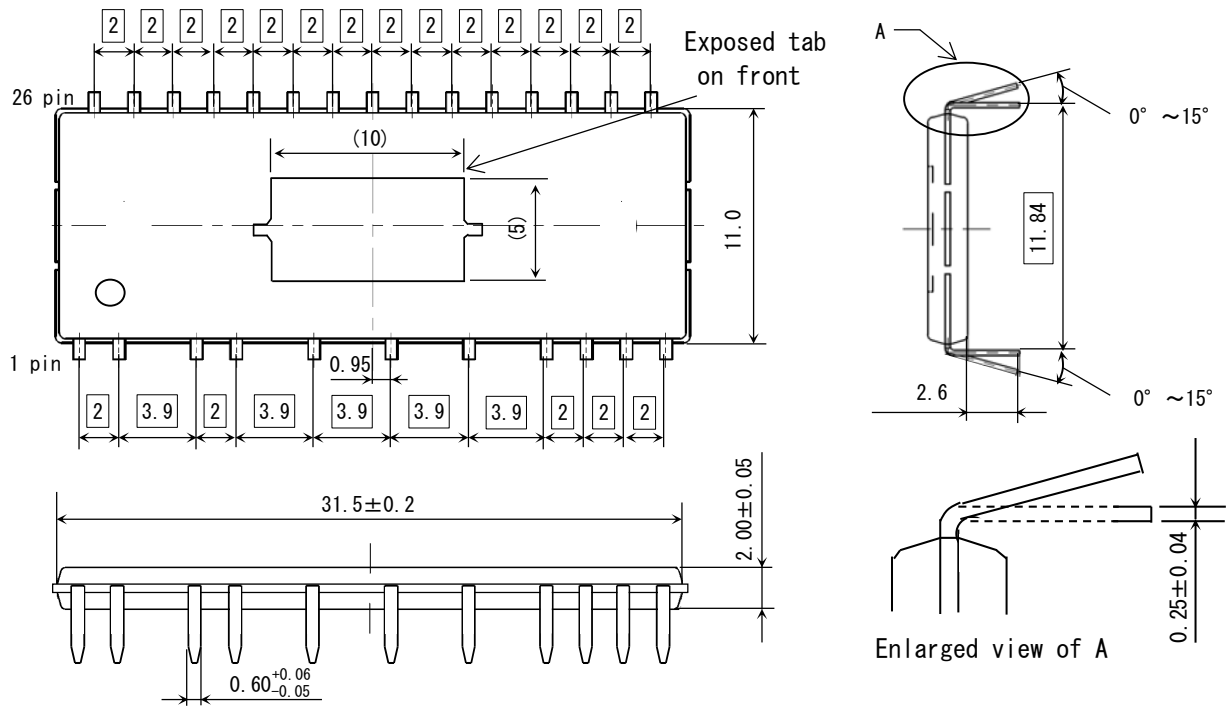
9. Usage

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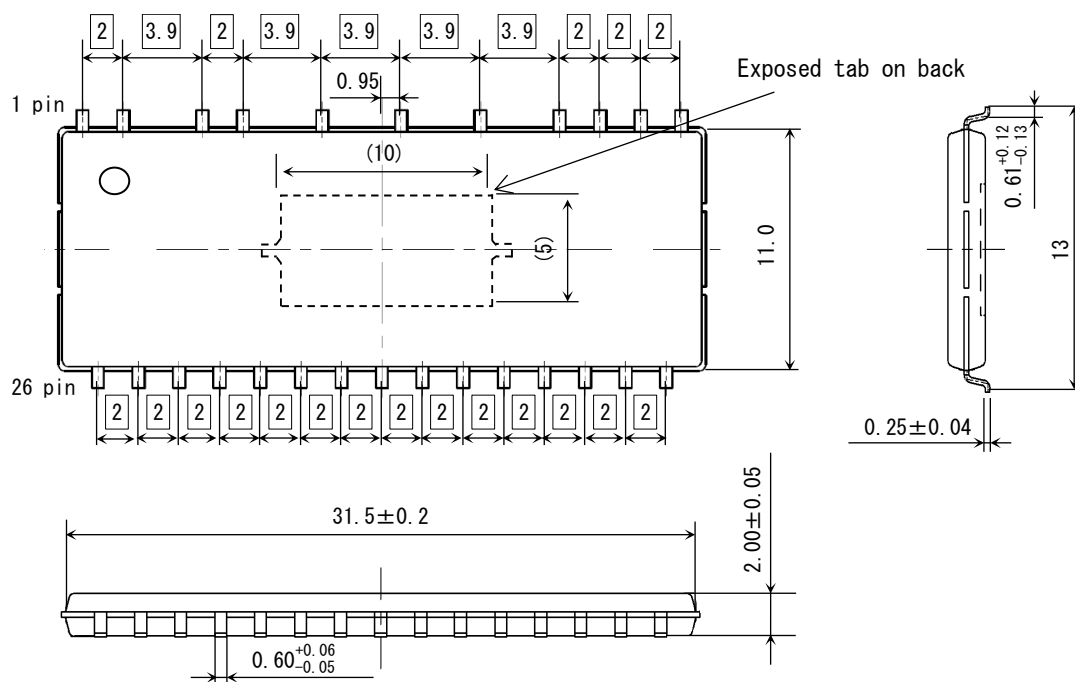
◆Appendix - Supplementary Data

1. Dimensions



Unit: mm

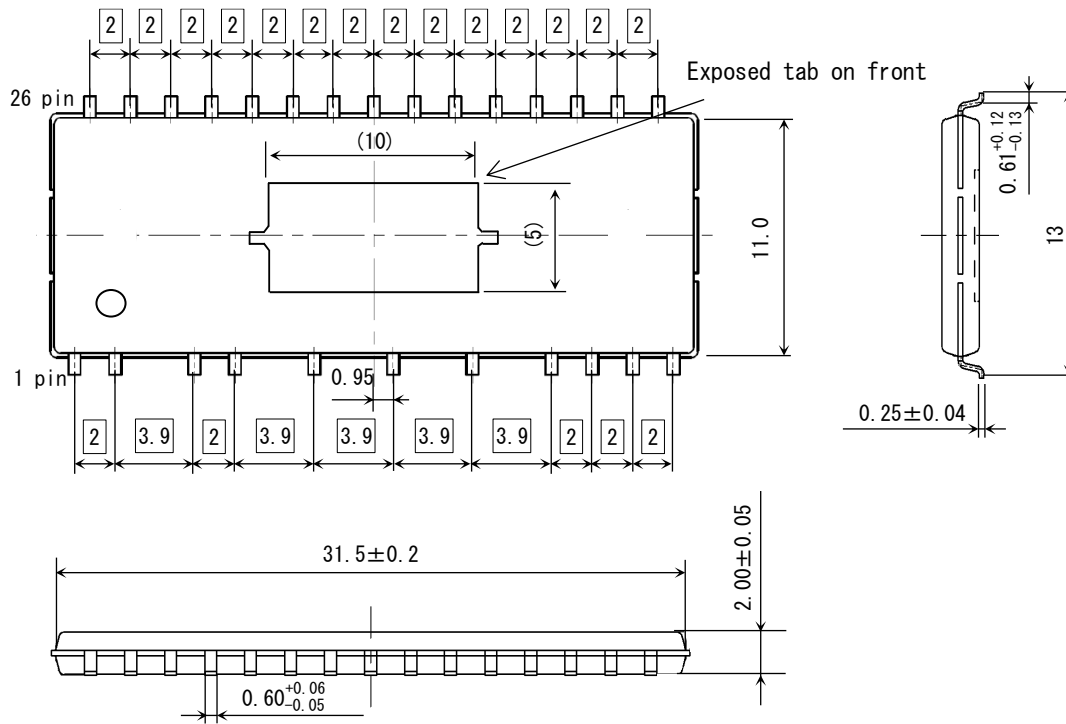
FIGURE A: Dimensions of DIP26



Unit: mm

FIGURE B: Dimensions of SOP26

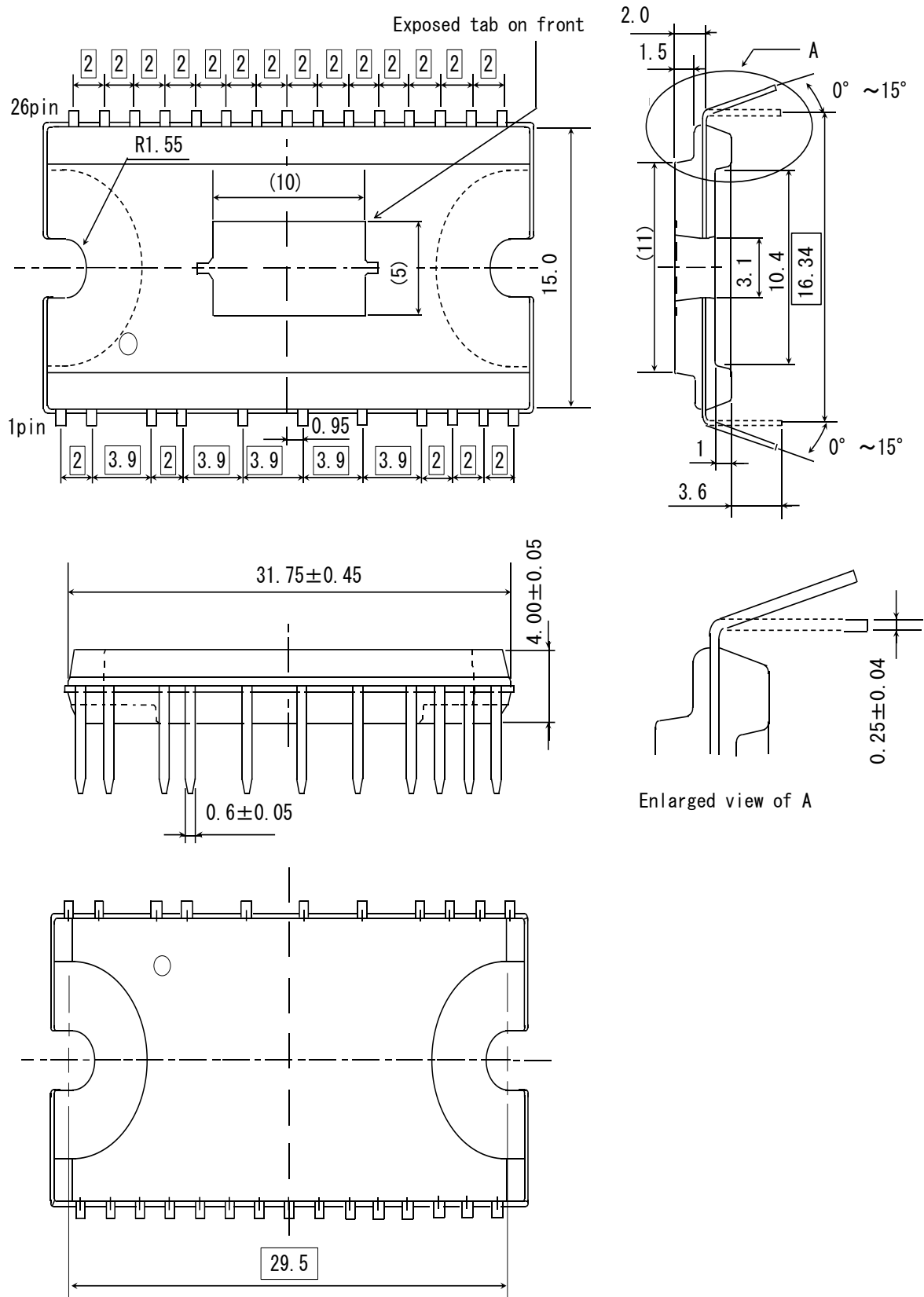
Note: Unless otherwise specified, the tolerance is ± 0.1 .



Unit: mm

FIGURE C: Dimensions of SOP26R

Note: Unless otherwise specified, the tolerance is ± 0.1 .



Unit: mm

Note: Unless otherwise specified, the tolerance is ± 0.1 .

2. External Packaging

FIGURE E shows the external packaging. The order quantity is basically the following.

- ECN30624P : 2,430 pcs or its multiple
- ECN30624F : 3,500 pcs or its multiple
- ECN30624R : 3,500 pcs or its multiple
- ECN30624PN : 1,620 pcs or its multiple

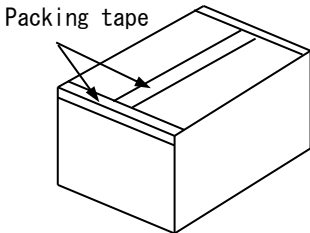
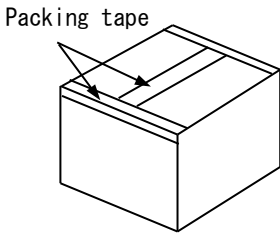
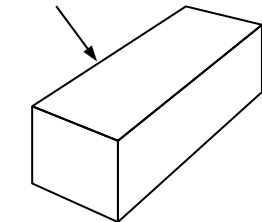
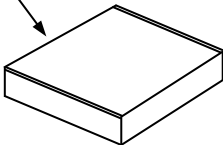
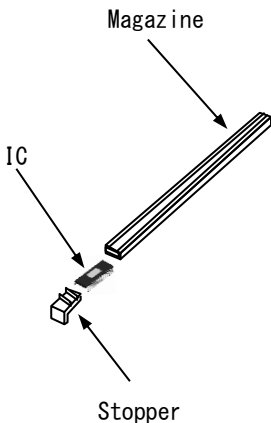
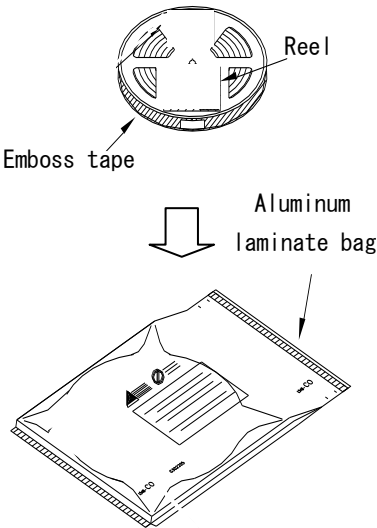
	Magazine (ECN30624P/ECN30624PN)	Reel (ECN30624F/ECN30624R)
Outer box		
Inner box		
Magazine & Reel	 The number of ICs: 15 pcs/magazine	 The number of ICs: 700 pcs/reel

FIGURE E: External Packaging